

International IOR Rectifier

16CTU04
16CTU04S
16CTU04-1

Ultrafast Rectifier

Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

$t_{rr} = 60ns$
$I_{F(AV)} = 16Amp$
$V_R = 400V$




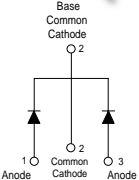
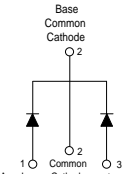
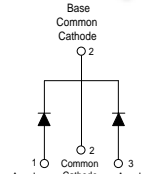
Description/ Applications

International Rectifier's FRED.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time. The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics. These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Peak Reverse Voltage	400	V
$I_{F(AV)}$ Average Rectified Forward Current	Per Leg	8
	Total Device, (Rated V_R), $T_C = 155^\circ C$	16
I_{FSM} Non Repetitive Peak Surge Current, $T_C = 25^\circ C$	100	A
I_{FRM} Peak Repetitive Forward Current (Rated V_R , Square wave, 20KHz), $T_C = 155^\circ C$	16	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	$^\circ C$

Case Styles

16CTU04	16CTU04S	16CTU04-1
		
<p>Base Common Cathode O 2</p>  <p>1 O Anode O 2 Common Cathode O 3 Anode</p> <p>TO-220AB</p>	<p>Base Common Cathode O 2</p>  <p>1 O Anode O 2 Common Cathode O 3 Anode</p> <p>D²PAK</p>	<p>Base Common Cathode O 2</p>  <p>1 O Anode O 2 Common Cathode O 3 Anode</p> <p>TO-262</p>

Electrical Characteristics @ $T_J = 25^\circ\text{C}$, Per Leg (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V_{BR}, V_r Breakdown Voltage, Blocking Voltage	400	-	-	V	$I_R = 100\mu\text{A}$
V_F Forward Voltage	-	1.19	1.3	V	$I_F = 8\text{A}$
	-	0.94	1.0	V	$I_F = 8\text{A}, T_J = 150^\circ\text{C}$
I_R Reverse Leakage Current	-	0.2	10	μA	$V_R = V_R \text{ Rated}$
	-	20	500	μA	$T_J = 150^\circ\text{C}, V_R = V_R \text{ Rated}$
C_T Junction Capacitance	-	14	-	pF	$V_R = 400\text{V}$
L_S Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_J = 25^\circ\text{C}$, Per Leg (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t_{rr} Reverse Recovery Time	-	35	60	ns	$I_F = 1.0\text{A}, di_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
	-	43	-		$T_J = 25^\circ\text{C}$
	-	67	-		$T_J = 125^\circ\text{C}$
I_{RRM} Peak Recovery Current	-	2.8	-	A	$T_J = 25^\circ\text{C}$
	-	6.3	-		$T_J = 125^\circ\text{C}$
Q_{rr} Reverse Recovery Charge	-	60	-	nC	$T_J = 25^\circ\text{C}$
	-	210	-		$T_J = 125^\circ\text{C}$

$I_F = 8\text{A}$
 $V_R = 200\text{V}$
 $di_F/dt = 200\text{A}/\mu\text{s}$

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T_J Max. Junction Temperature Range	-	-	175	$^\circ\text{C}$
T_{Stg} max. Storage Temperature Range	- 65	-	175	
R_{thJC} Thermal Resistance, Junction to Case	-	1.8	2	$^\circ\text{C}/\text{W}$
R_{thJA} ① Thermal Resistance, Junction to Ambient	-	-	50	
R_{thCS} ② Thermal Resistance, Case to Heatsink	-	0.5	-	
Wt Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in

① Typical Socket Mount

② Mounting Surface, Flat, Smooth and Greased

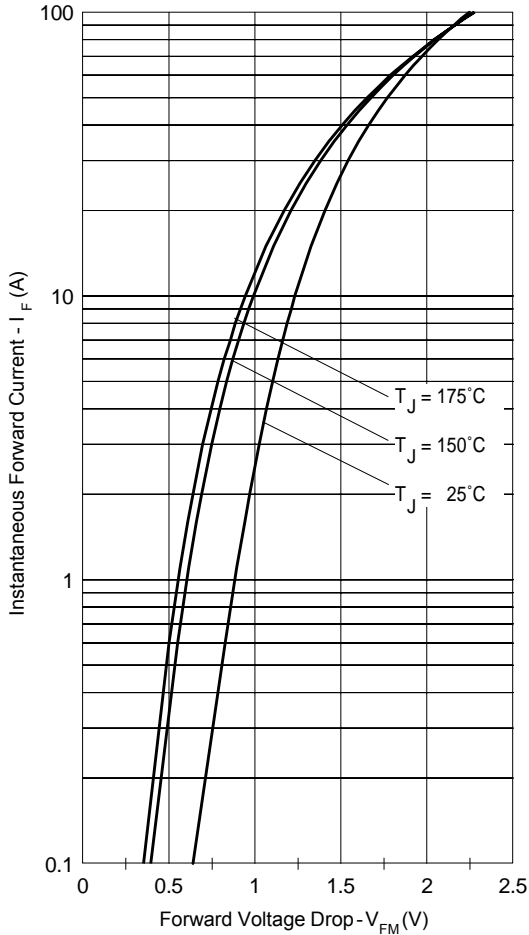


Fig. 1 - Typical Forward Voltage Drop Characteristics

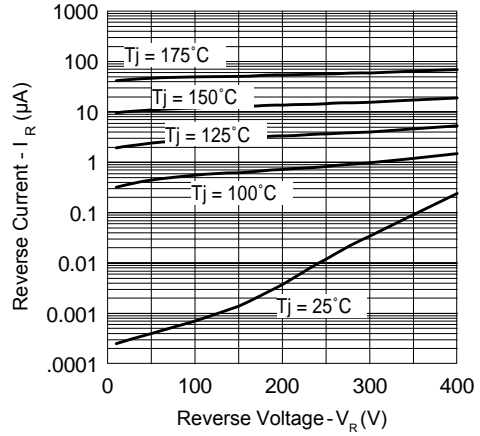


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

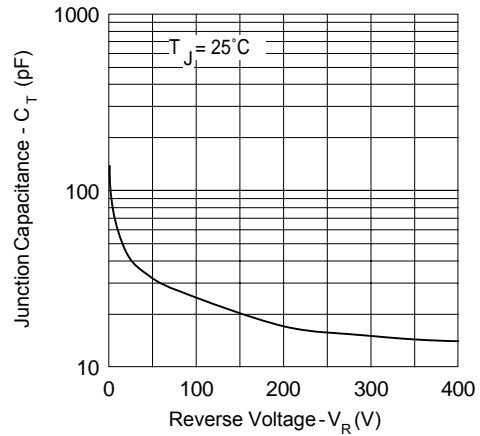


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

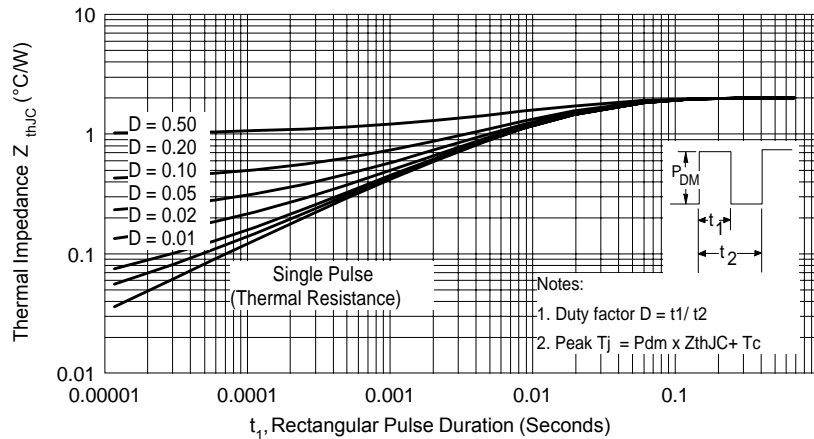


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

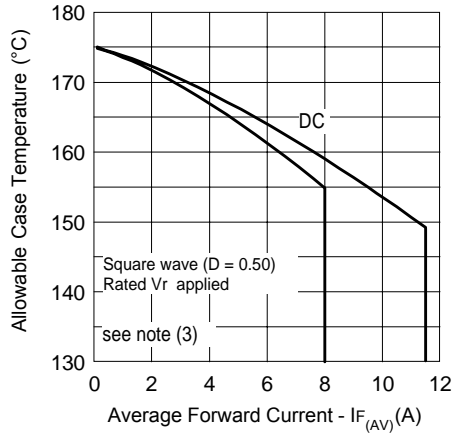


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

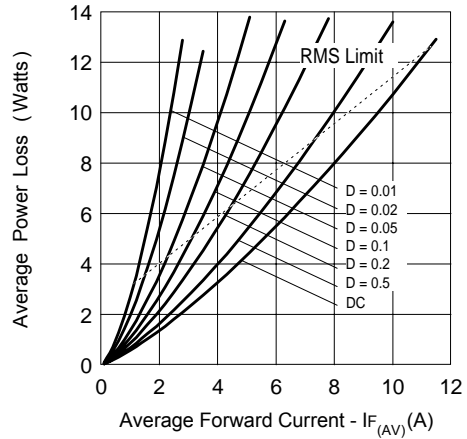


Fig. 6 - Forward Power Loss Characteristics

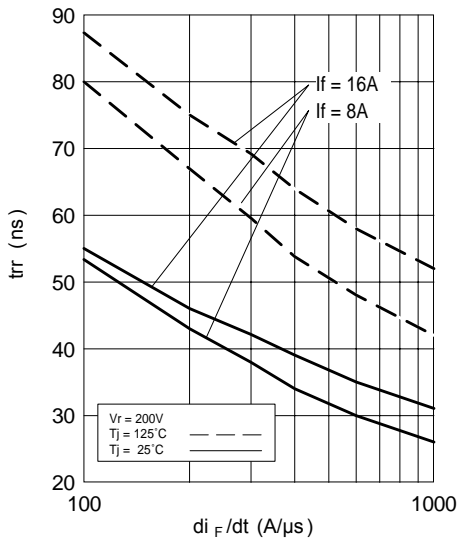


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

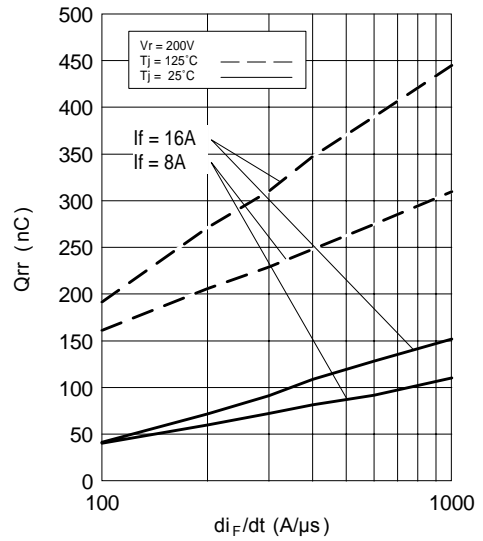


Fig. 8 - Typical Stored Charge vs. di_F/dt

(3) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = \text{rated } V_R$

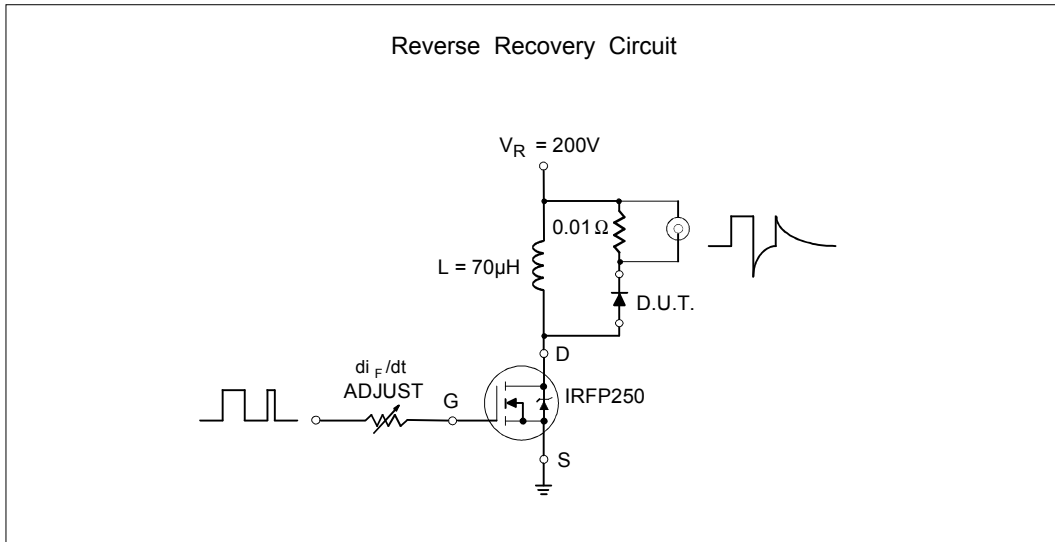


Fig. 9- Reverse Recovery Parameter Test Circuit

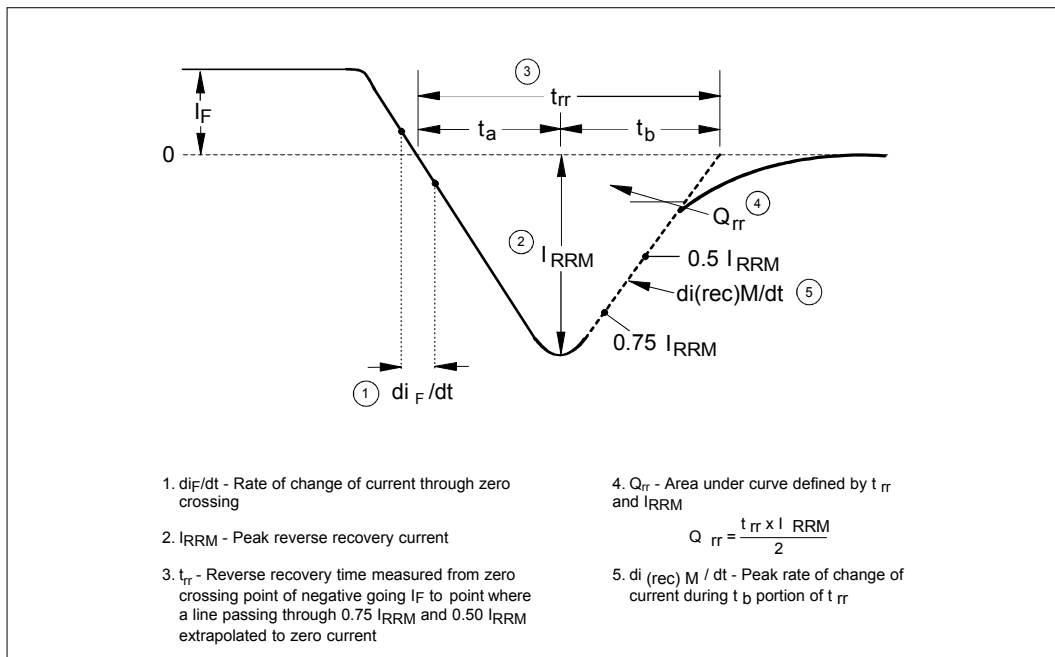
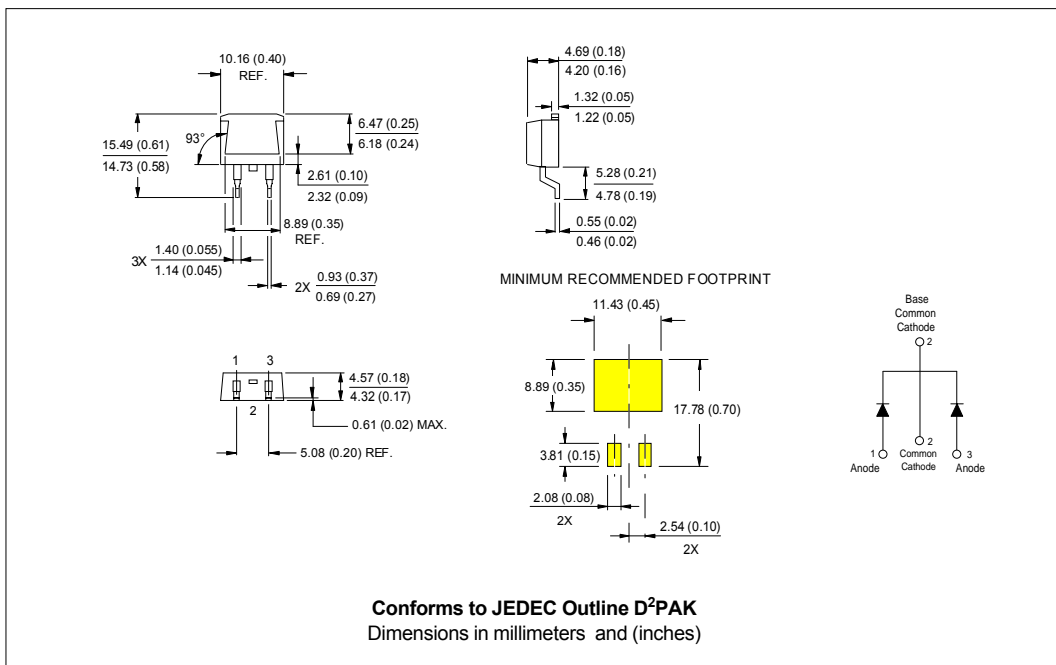
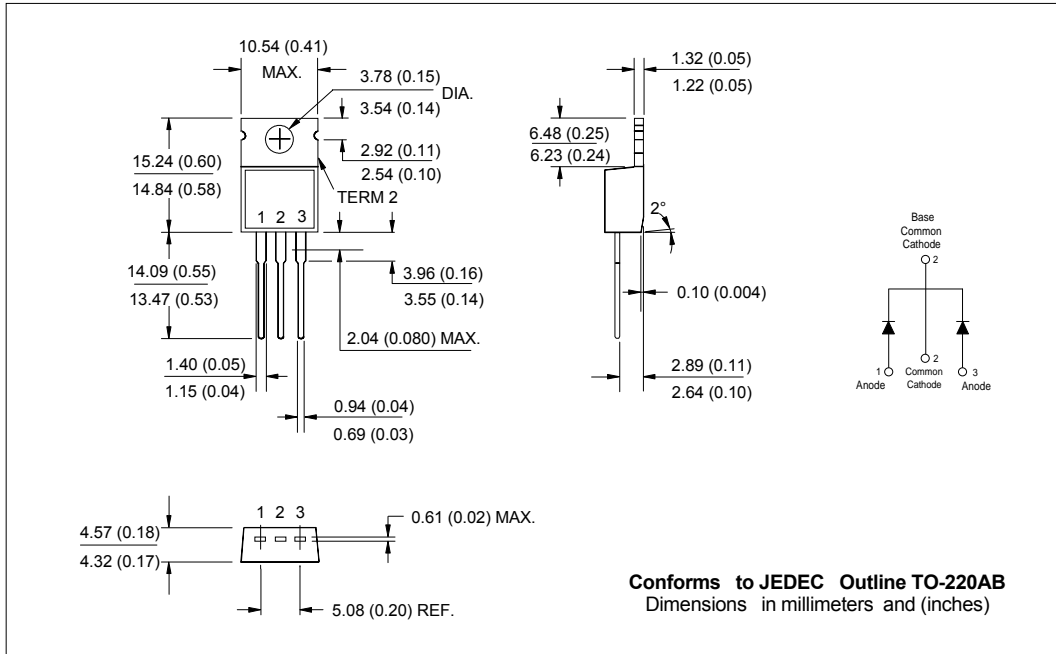
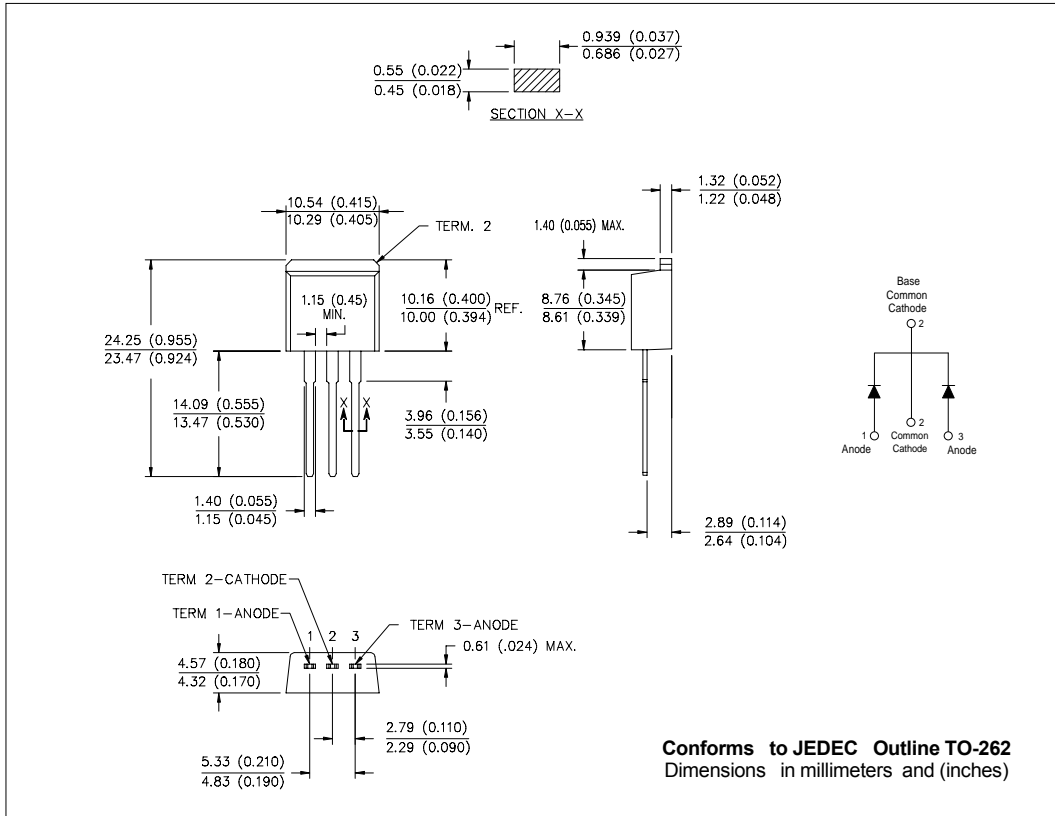


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table



Outline Table



Ordering Information Table

Device Code					
16	C	T	U	04	- 1
①	②	③	④	⑤	⑥
1	- Current Rating (16 = 16A)				
2	- Common Cathode				
3	- TO-220/ D ² Pak				
4	- Ultrafast Recovery				
5	- Voltage Rating (04 = 400V)				
6	- Suffix for SMD type -1: TO-262 Option S: TO-220 SMD (D ² Pak)				

16CTU04, 16CTU04S, 16CTU04-1

Bulletin PD-20752 rev. A 11/01

International
IR Rectifier

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 11/01